

Ultrafast recovery - high voltage diode

Main product characteristics

$I_{F(AV)}$	8 A
V_{RRM}	1000 V
T_j	175° C
V_F (typ)	1.30 V
t_{rr} (typ)	47 ns

Features and benefits

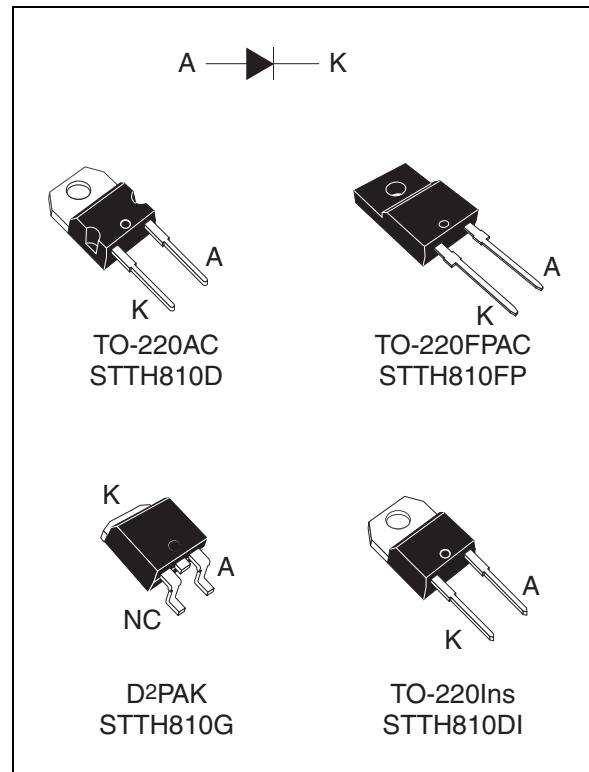
- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- Insulated packages:
 - TO-220Ins
 - Electrical insulation = 2500 V_{RMS}
Capacitance = 7 pF
 - TO-220FPAC
Electrical insulation = 2500 V_{RMS}
Capacitance = 12 pF

Description

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

Such demanding applications include industrial power supplies, motor control, and similar mission-critical systems that require rectification and freewheeling. These diodes also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device.



Order codes

Part Number	Marking
STTH810D	STTH810D
STTH810G	STTH810G
STTH810G-TR	STTH810G
STTH810FP	STTH810FP
STTH810DI	STTH810DI

1 Characteristics

Table 1. Absolute ratings (limiting values at 25° C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			1000	V
I _{F(RMS)}	RMS forward current	TO-220AC / D ² PAK / TO-220FPAC			30
		TO-220AC Ins			20
I _{F(AV)}	Average forward current, $\delta = 0.5$	TO-220AC / D ² PAK	T _c = 130° C	8	A
		TO-220FPAC	T _c = 75° C		
		TO-220AC Ins	T _c = 105° C		
I _{FRM}	Repetitive peak forward current	t _p = 5 µs, F = 5 kHz square		100	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sinusoidal		60	A
T _{stg}	Storage temperature range			-65 to + 175	°C
T _j	Maximum operating junction temperature			175	°C

Table 2. Thermal parameters

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case	TO-220AC / D ² PAK		2.5	°C/W
		TO-220FPAC		5.8	
		TO-220AC Ins		4.1	

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25° C	V _R = V _{RRM}			5	µA
		T _j = 125° C			2	20	
V _F ⁽²⁾	Forward voltage drop	T _j = 25° C	I _F = 8 A			2	V
		T _j = 100° C			1.4	1.8	
		T _j = 150° C			1.3	1.7	

1. Pulse test: t_p = 5 ms, δ < 2 %2. Pulse test: t_p = 380 µs, δ < 2 %

To evaluate the conduction losses use the following equation:

$$P = 1.3 \times I_{F(AV)} + 0.05 I_{F(RMS)}^2$$

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 1 \text{ A}, dI_F/dt = -50 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}, T_j = 25^\circ \text{C}$		64	85	ns
		$I_F = 1 \text{ A}, dI_F/dt = -100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}, T_j = 25^\circ \text{C}$		47	65	
I_{RM}	Reverse recovery current	$I_F = 8 \text{ A}, dI_F/dt = -200 \text{ A}/\mu\text{s}, V_R = 600 \text{ V}, T_j = 125^\circ \text{C}$		12	16	A
S	Softness factor	$I_F = 8 \text{ A}, dI_F/dt = -200 \text{ A}/\mu\text{s}, V_R = 600 \text{ V}, T_j = 125^\circ \text{C}$		2		
t_{fr}	Forward recovery time	$I_F = 8 \text{ A}, dI_F/dt = 50 \text{ A}/\mu\text{s}, V_{FR} = 1.5 \times V_{Fmax}, T_j = 25^\circ \text{C}$			300	ns
V_{FP}	Forward recovery voltage	$I_F = 8 \text{ A}, dI_F/dt = 50 \text{ A}/\mu\text{s}, T_j = 25^\circ \text{C}$		5.5		V

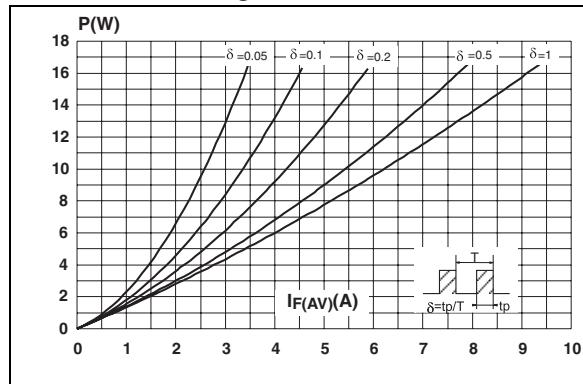
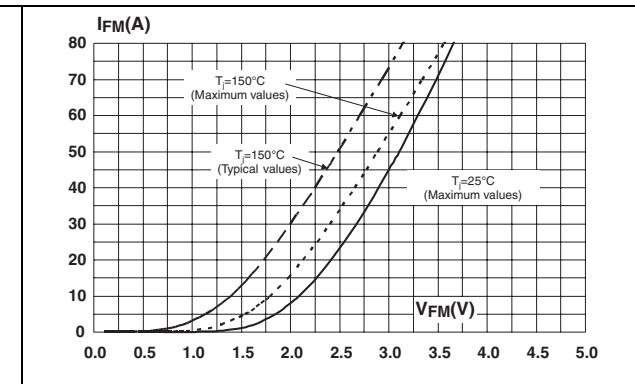
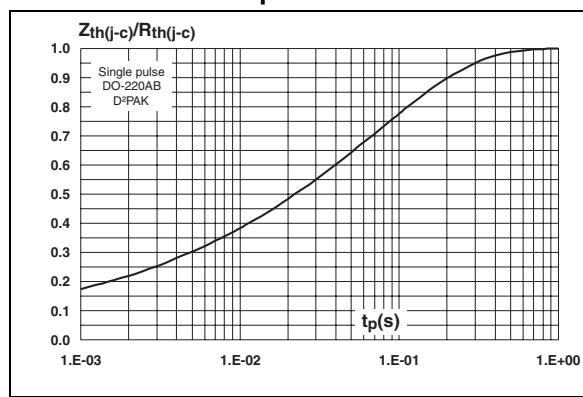
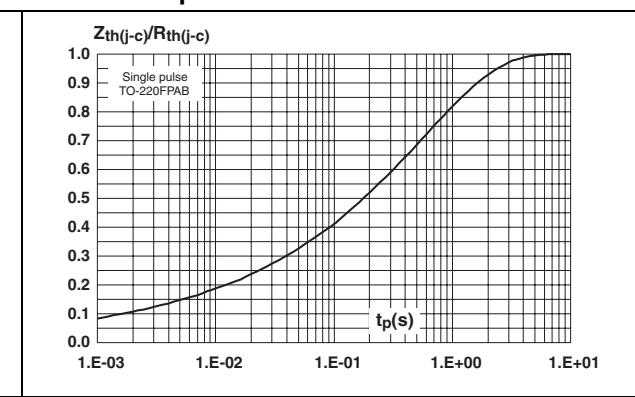
Figure 1. Conduction losses versus average current**Figure 2. Forward voltage drop versus forward current****Figure 3. Relative variation of thermal impedance junction to case versus pulse duration****Figure 4. Relative variation of thermal impedance junction to case versus pulse duration**

Figure 5. Peak reverse recovery current versus dI_F/dt (typical values)

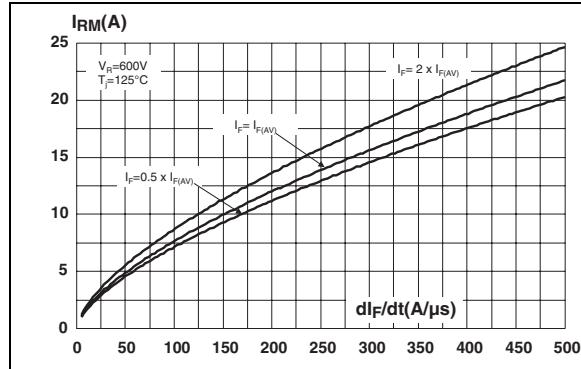


Figure 6. Reverse recovery time versus dI_F/dt (typical values)

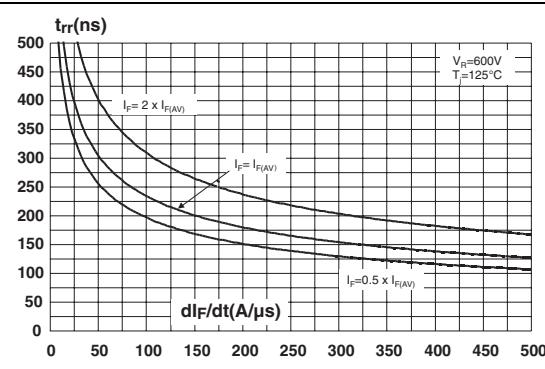


Figure 7. Reverse recovery charges versus dI_F/dt (typical values)

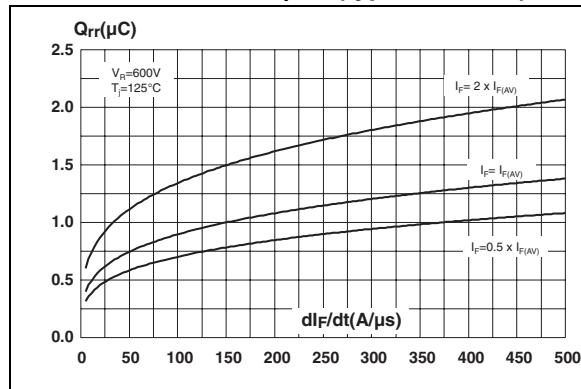


Figure 8. Softness factor versus dI_F/dt (typical values)

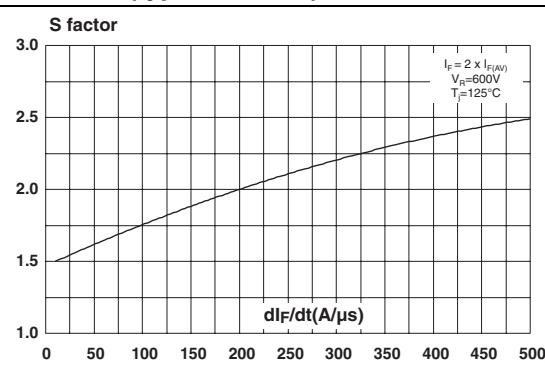


Figure 9. Relative variations of dynamic parameters versus junction temperature

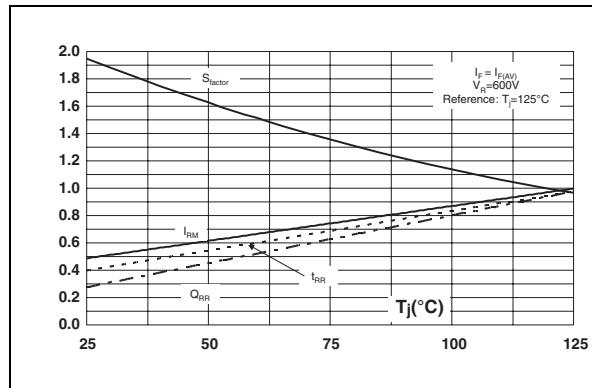
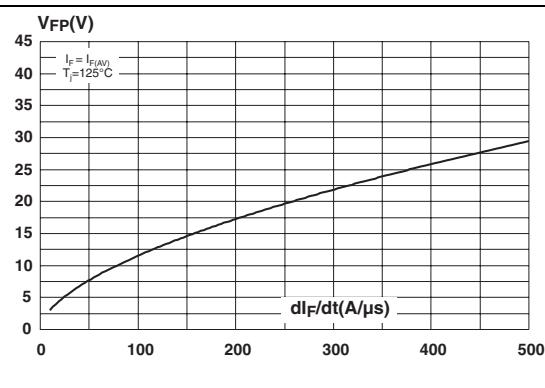


Figure 10. Transient peak forward voltage versus dI_F/dt (typical values)



3 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH810D	STTH810D	TO-220AC	1.86 g	50	Tube
STTH810DI	STTH810DI	TO-220Ins	1.86 g	50	Tube
STTH810FP	STTH810FP	TO-220FPAC	2.2 g	50	Tube
STTH810G	STTH810G	D ² PAK	1.48 g	50	Tube
STTH810G-TR	STTH810G	D ² PAK	1.48 g	1000	Tape & reel